

TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

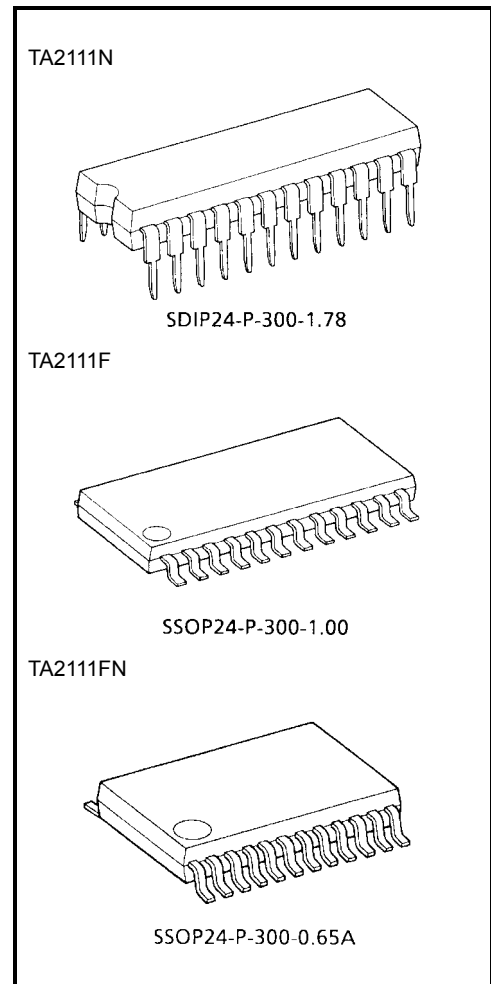
# TA2111N, TA2111F, TA2111FN

## 3 V AM/FM 1 Chip Tuner IC

TA2111N/F/FN are AM/FM 1 chip tuner ICs, which are designed for portable radios and 3 V Head phone radios. FM local oscillation voltage is set up low relativity, for NEW FCC.

### Features

- For NEW FCC.
- AM Detector coil, FM IFT, IF coupling condenser are not needed.
- For adopting ceramic discriminator, it is not necessary to adjust the FM quad detector circuit.
- Built-in FM MPX VCO circuit.
- Built-in varactor diode for AFC.
- Built-in AM low cut circuit.
- Low supply current. (VCC = 3 V, Ta = 25°C)  
 ICCq (FM) = 9.0 mA (typ.)  
 ICCq (AM) = 5.0 mA (typ.)
- Operating supply voltage range: VCC = 1.8~7 V (Ta = 25°C)

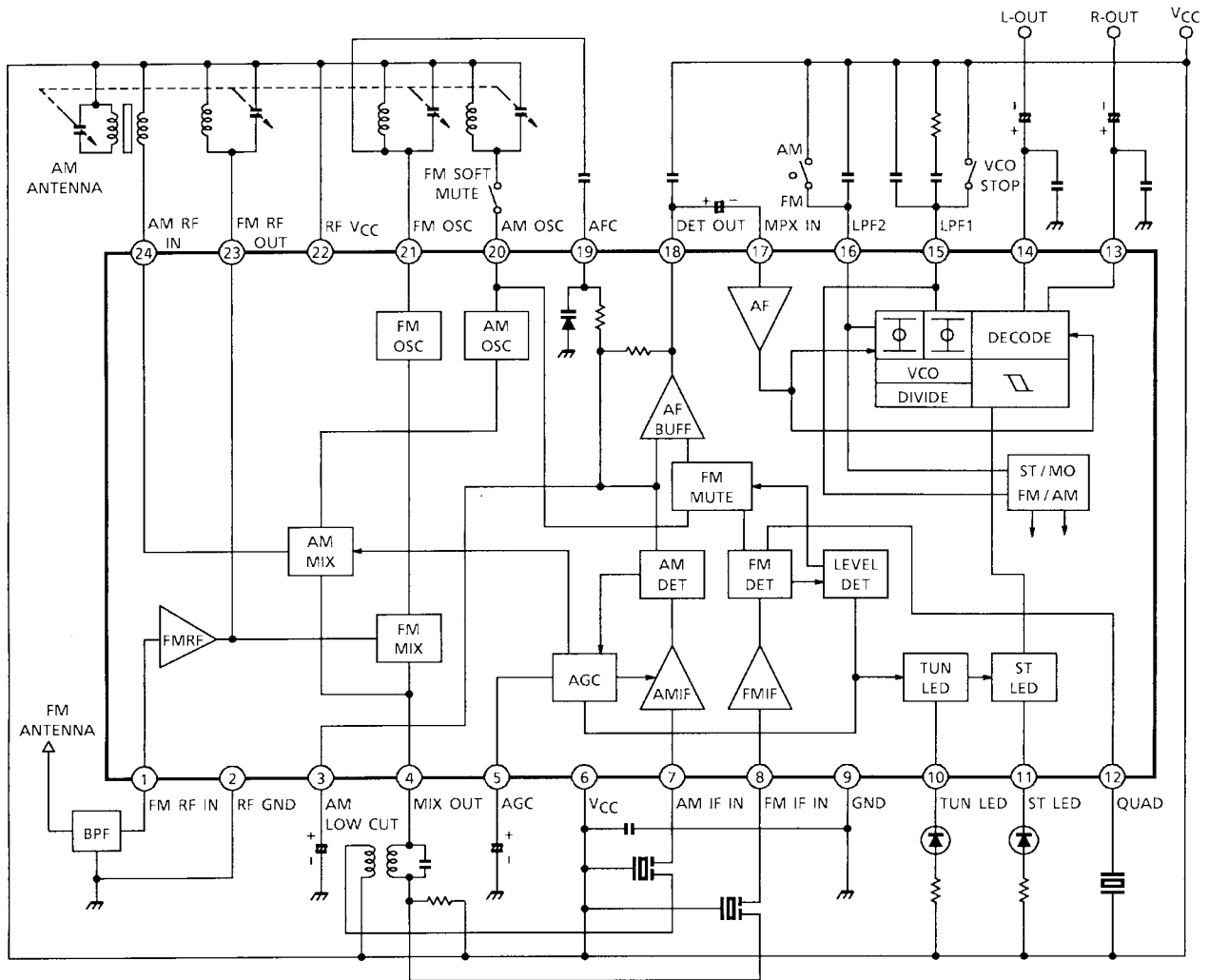


**Weight**

- SDIP24-P-300-1.78: 1.2 g (typ.)
- SSOP24-P-300-1.00: 0.31 g (typ.)
- SSOP24-P-300-0.65A: 0.14 g (typ.)

Note 1: Handle with care to prevent devices from deteriorations by static electricity.

## Block Diagram



## Explanation of Terminals

(Terminal voltage: Typical terminal voltage at no signal with test circuit,  $V_{CC} = 3\text{ V}$ ,  $T_a = 25^\circ\text{C}$ )

Pin No.	Characteristics	Internal Circuit	Terminal Voltage (Typ.) (V)	
			AM	FM
1	FM-RF IN		0	0.8
2	RF GND (GND for FM RF, FM OSC stage)	—	0	0
3	AM LOW CUT		1.0	0.8
4	MIX OUT		3.0	2.9
5	AGC (AM AGC)		0	0
6	$V_{CC}$ ( $V_{CC}$ for AM, FM IF, FM MPX stage)	—	3.0	3.0
7	AM IF IN		2.3	2.6

Pin No.	Characteristics	Internal Circuit	Terminal Voltage (Typ.) (V)	
			AM	FM
8	FM IF IN		3.0	3.0
9	GND (GND for AM, FM IF, FM MPX stage)	—	0	0
10	TUN LED (Tuning LED)		—	—
11	ST LED (Stereo LED)		—	—
12	QUAD (FM QUAD. Detector)		2.5	2.2
13 14	R-OUT (R-ch Output) L-OUT (L-ch Output)		1.2	1.2

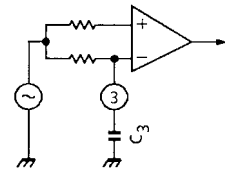
Pin No.	Characteristics	Internal Circuit	Terminal Voltage (Typ.) (V)	
			AM	FM
15	<p>LPF1</p> <ul style="list-style-type: none"> <li>• LPF terminal for synchronous Detector</li> <li>• VCO stop terminal</li> </ul> <p>V15 = V<sub>CC</sub> → VCO STOP</p>		2.3	2.3
16	<p>LPF2</p> <ul style="list-style-type: none"> <li>• LPF terminal for phase Detector</li> <li>• Bias terminal for AM/FM SW circuit</li> </ul> <p>V16 = V<sub>CC</sub> → AM V16 = OPEN → FM</p>		3	2.2
17	MPX IN		0.7	0.7
18	DET OUT	<p>(A) LOW→FM, HIGH→AM (B) LOW→AM, HIGH→FM</p>	1.0	0.9

Pin No.	Characteristics	Internal Circuit	Terminal Voltage (Typ.) (V)	
			AM	FM
19	AFC	cf. pin 3	—	—
20	AM OSC		3.0	3.0
21	FM OSC		3.0	3.0
22	RF V <sub>CC</sub> (V <sub>CC</sub> for FM OSC stage)	—	3.0	3.0
23	FM RF OUT	cf. pin 1	3.0	3.0
24	AM RF IN		3.0	3.0

## Application Note

### 1. AM low-cut circuit

- The AM Low-Cut action is carried out by the bypass of the high frequency component of the positive-feedback signal at the AF AMP stage. The external capacitor: C<sub>3</sub> by-passes this component.
- The cut-off frequency f<sub>L</sub> is determined by the internal resistance 10 kΩ (typ.) and the external capacitor C<sub>3</sub> as following ;

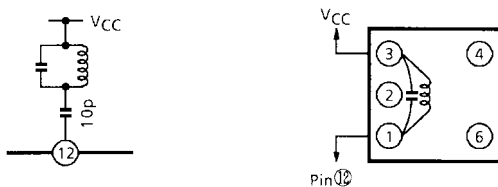


$$f_L = \frac{1}{2 \times \pi \times 10 \times 10^3 \times C_3} \text{ (Hz)}$$

- In the case of the AM Low-Cut function is not needed, set up the value of C<sub>3</sub> over 1 μF. In the condition of C<sub>3</sub> ≥ 1 μF, the frequency characteristic has flat response at the low frequency.
- In FM mode, C<sub>3</sub> is a capacitor for AFC Low-Pass filter circuit.

### 2. FM detection circuit

For the FM detection circuit, detection coil is able to use instead of ceramic discriminator. Recommended circuit and recommended coil are as follows. In this case, please take care that V<sub>in</sub> (lim.) falls a little.



Test Frequency	C <sub>o</sub> (pF)	Q <sub>o</sub>	Turns				Wire (mmφ)	Reference
			1-2	2-3	1-3	4-6		
10.7 MHz	51	45	—	—	30	—	0.08 UEW	TOKO Co., Ltd. 600BEAS-10018Z

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	8	V
LED current	I <sub>LED</sub>	10	mA
LED voltage	V <sub>LED</sub>	8	V
Power dissipation	TA2111N	P <sub>D</sub> (Note 2)	1200
	TA2111F		400
	TA2111FN		500
Operating temperature	T <sub>opr</sub>	-25~75	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C

Note 2: Derated above Ta = 25°C in the proportion of 9.6 mW/°C for TA2111N, of 3.2 mW/°C for TA2111F and of 4 mW/°C for TA2111FN.

## Electrical Characteristics

unless otherwise specified,  $T_a = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$ ,

F/E :  $f = 98\text{ MHz}$ ,  $f_m = 1\text{ kHz}$

FM IF :  $f = 10.7\text{ MHz}$ ,  $\Delta f = \pm 22.5\text{ kHz}$ ,  $f_m = 1\text{ kHz}$

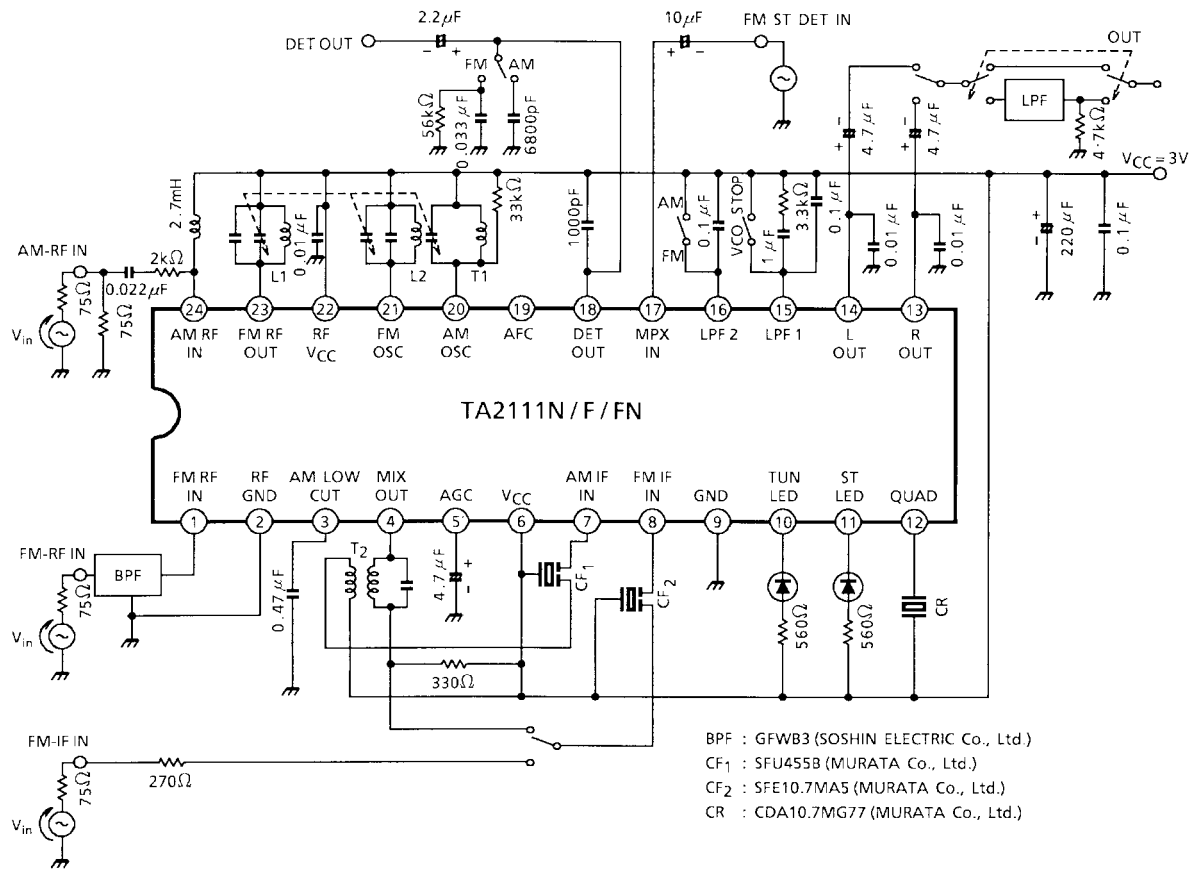
AM :  $f = 1\text{ MHz}$ ,  $\text{MOD} = 30\%$ ,  $f_m = 1\text{ kHz}$

MPX :  $f_m = 1\text{ kHz}$

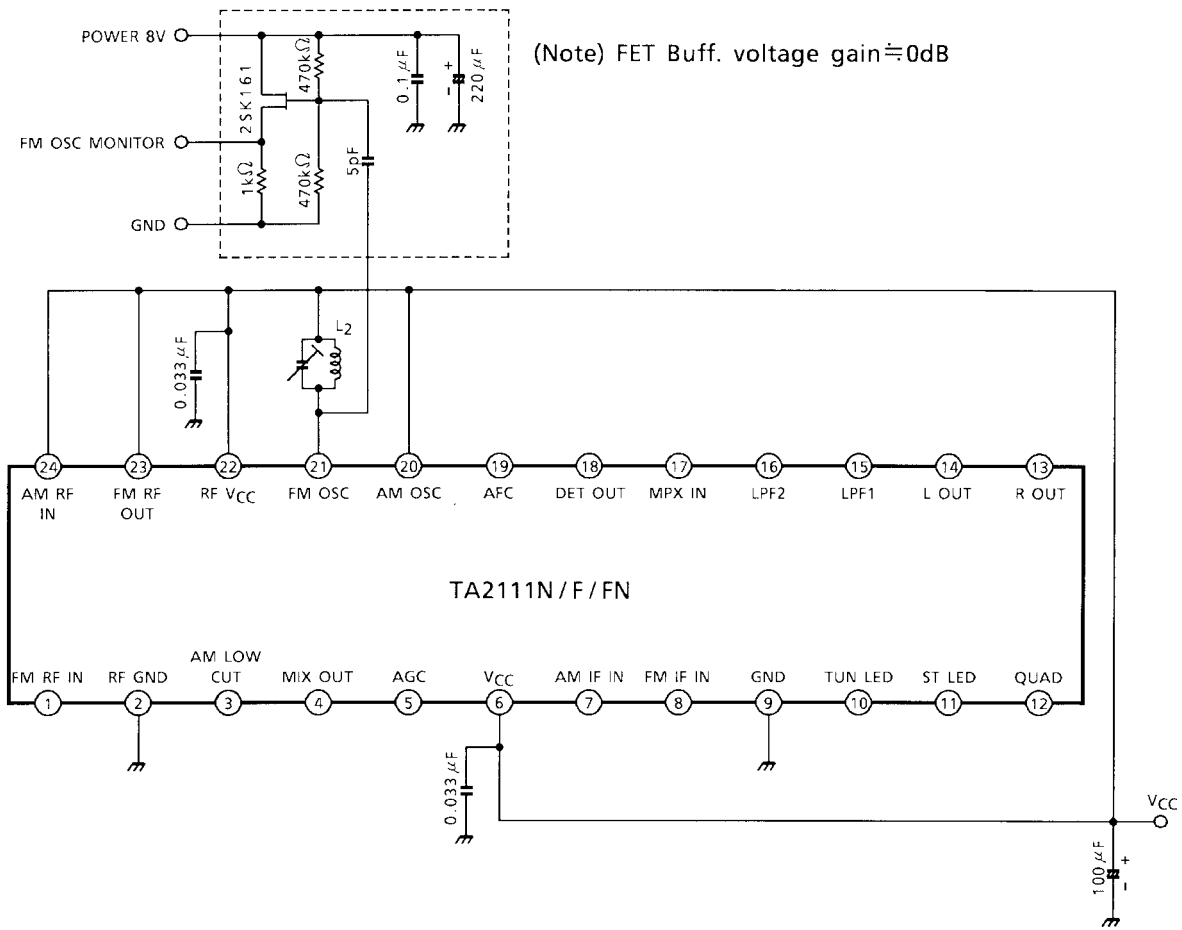
Characteristics		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit		
Supply current		$I_{CC}(\text{FM})$	1	$V_{in} = 0$ , FM mode	—	9	12.5	mA		
		$I_{CC}(\text{AM})$	1	$V_{in} = 0$ , AM mode	—	5	7.5			
F/E	Input limiting voltage	$V_{in}(\text{lim})$	1	-3dB limiting	—	7	—	dB $\mu$ V EMF		
	Local OSC voltage	$V_{OSC}$	2	$f_{OSC} = 108.7\text{ MHz}$	—	105	—		mVrms	
FM IF	Input limiting voltage	$V_{in}(\text{lim})\text{ IF}$	1	-3dB limiting	35	40	45	dB $\mu$ V EMF		
	Recovered output voltage	$V_{OD}$	1	$V_{in} = 80\text{dB}\mu\text{V EMF}$	60	75	90		mVrms	
	Signal to noise ratio	S/N	1	$V_{in} = 80\text{dB}\mu\text{V EMF}$	—	65	—	dB		
	Total harmonic distortion	THD	1	$V_{in} = 80\text{dB}\mu\text{V EMF}$	—	0.2	—	%		
	AM rejection ration	AMR	1	$V_{in} = 80\text{dB}\mu\text{V EMF}$	—	45	—	dB		
	LED on sensitivity	$V_L$	1	$I_L = 1\text{ mA}$	40	45	50	dB $\mu$ V EMF		
	Soft mute attenuation	MUTE	1	$V_{in} = 0$	—	20	—		dB	
AM	Gain	$G_V$	1	$V_{in} = 25\text{dB}\mu\text{V EMF}$	18	35	70	mVrms		
	Recovered output voltage	$V_{OD}$	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	50	70	90		mVrms	
	Signal to noise ratio	S/N	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	—	41	—	dB		
	Total harmonic distortion	THD	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	—	0.7	—	%		
	LED on sensitivity	$V_L$	1	$I_L = 1\text{ mA}$	23	28	33	dB $\mu$ V EMF		
Pin 18 output resistance		$R_{18}$	—	FM mode	—	0.75	—		k $\Omega$	
				AM mode	—	15.5	—			
MPX	Input resistance		$R_{IN}$	—	—	55	—	k $\Omega$		
	Output resistance		$R_{OUT}$	—	—	5	—	k $\Omega$		
	Max composite signal input voltage		$V_{in}\text{ MAX (STEREO)}$	1	$L + R = 90\%$ , $P = 10\%$ , $f_m = 1\text{ kHz}$ , $\text{THD} = 3\%$	—	700	—	mVrms	
	Separation		Sep	1	$L + R = 180\text{ mVrms}$ , $P = 20\text{ mVrms}$	$f_m = 100\text{ Hz}$	—	45	—	dB
						$f_m = 1\text{ kHz}$	—	45	—	
						$f_m = 10\text{ kHz}$	—	45	—	
	Total harmonic distortion	Monaural	THD (MONAURAL)	1	$V_{in} = 200\text{ mVrms}$	—	0.3	—	%	
		Stereo	THD (STEREO)	1	$L + R = 180\text{ mVrms}$ , $P = 20\text{ mVrms}$	—	0.3	—		
	Voltage gain		$G_V$	1	$V_{in} = 200\text{ mVrms}$	-2.5	-1	0.5	dB	
	Channel balance		C.B.	1	$V_{in} = 200\text{ mVrms}$	-1.5	0	1.5	dB	
	Stereo LED sensitivity	ON	$V_L(\text{ON})$	1	Pilot input	—	8	12	mVrms	
		OFF	$V_L(\text{OFF})$	1		3	6	—		
	Stereo LED hysteresis		$V_H$	1	To LED turn off from LED turn on	—	2	—	mVrms	
	Capture range		C.R.	1	$P = 20\text{ mVrms}$	—	$\pm 8$	—	%	
Signal to noise ratio		S/N	1	—	—	80	—	dB		



## Test Circuit 1



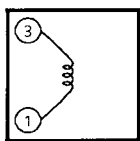
## Test Circuit 2



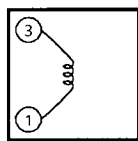
## Coil Data

Coil No.	Test Freq.	L ( $\mu$ H)	C <sub>0</sub> (pF)	Q <sub>0</sub>	Turns					Wire (mm $\phi$ )	Reference
					1-2	2-3	1-3	1-4	4-6		
L <sub>1</sub> FM RF	100 MHz	—	—	79	—	—	—	2 $\frac{1}{2}$	—	0.16UEW	TOKO Co., Ltd. 666SNF-305NK
L <sub>2</sub> FM OSC	100 MHz	—	—	76	—	—	—	2	—	0.16UEW	TOKO Co., Ltd. 666SNF-306NK
T <sub>1</sub> AM OSC	796 kHz	268	—	65	19	95	—	—	—	0.05UEW	TOKO Co., Ltd. 5PNR-5146Y
T <sub>2</sub> AM IFT	455 kHz	—	470	60	—	—	109	—	7	0.05UEW	TOKO Co., Ltd. 5PLG-5147X

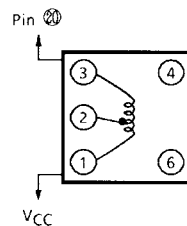
L<sub>1</sub> : FM RF



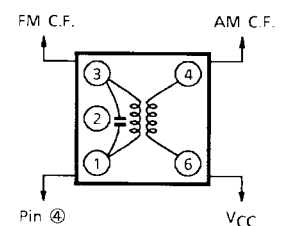
L<sub>2</sub> : FM OSC



T<sub>1</sub> : AM OSC

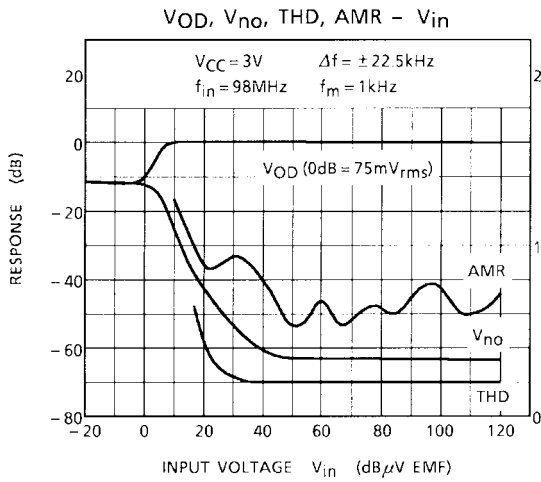


T<sub>2</sub> : AM IFT

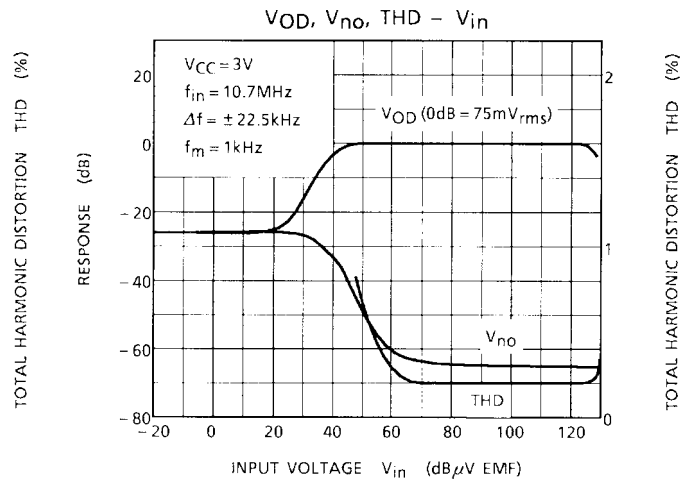


(BOTTOM VIEW)

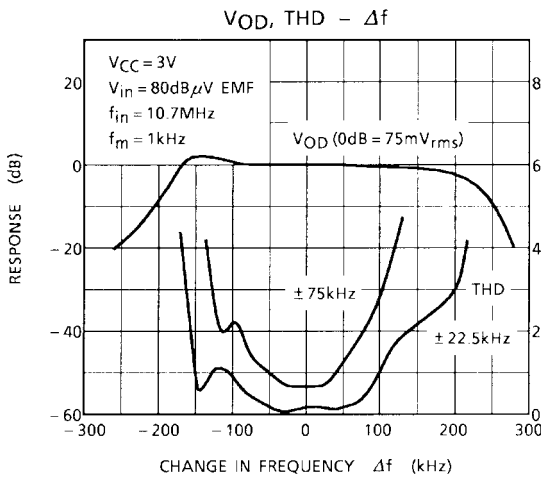
FM (F/E+IF)



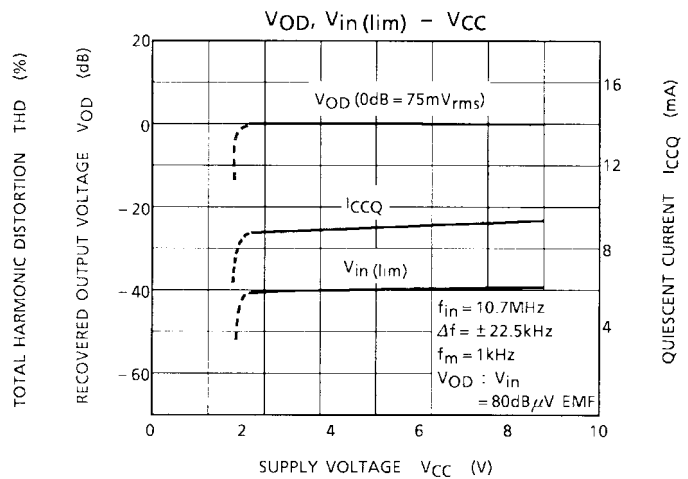
FM (IF)



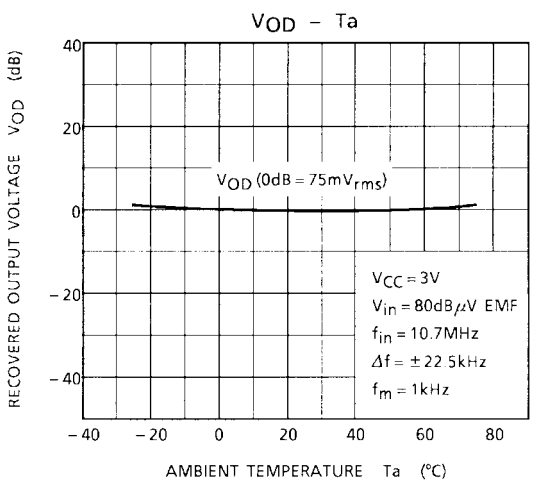
FM (IF)



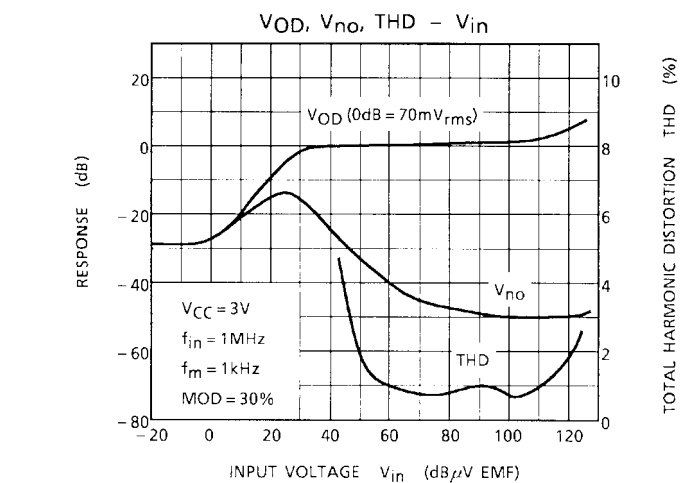
FM (IF)



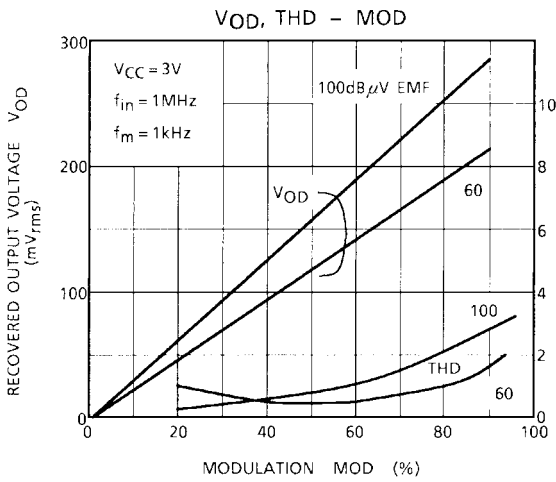
FM (IF)



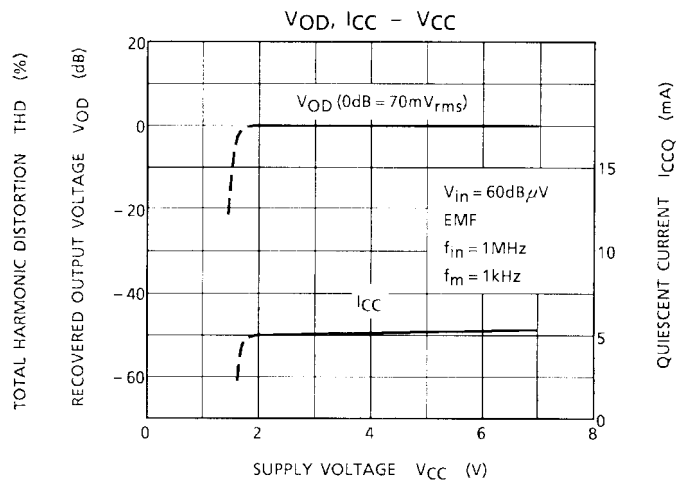
AM



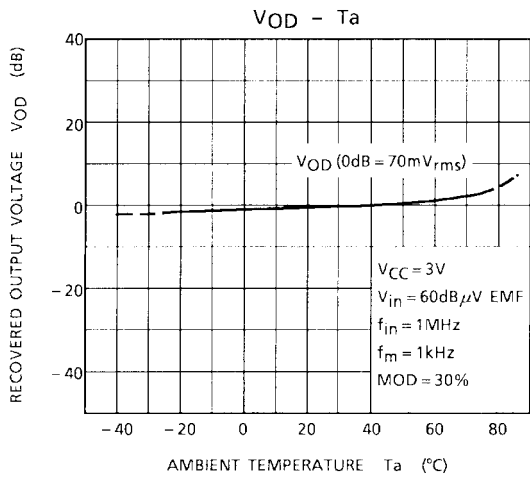
AM



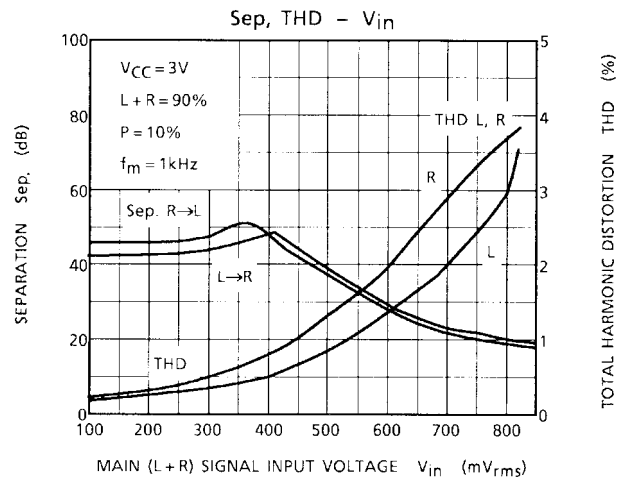
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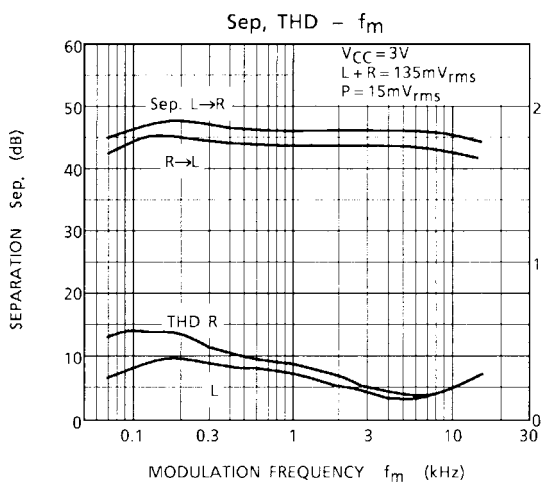
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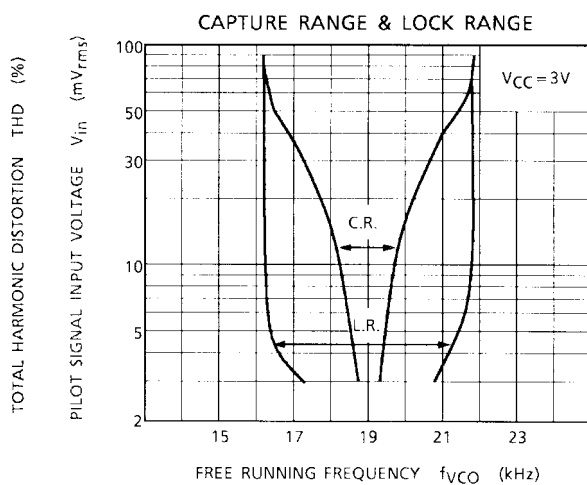
MPX



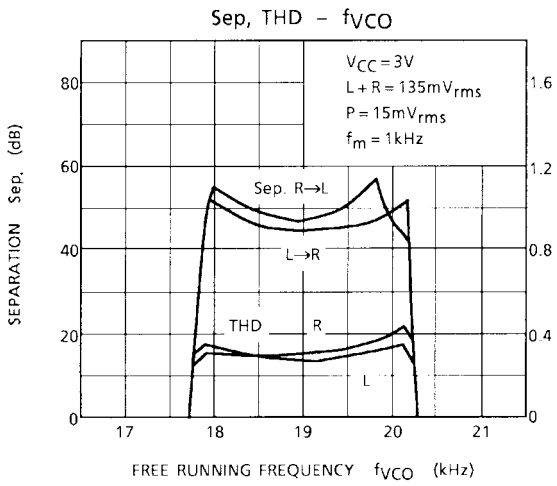
MPX



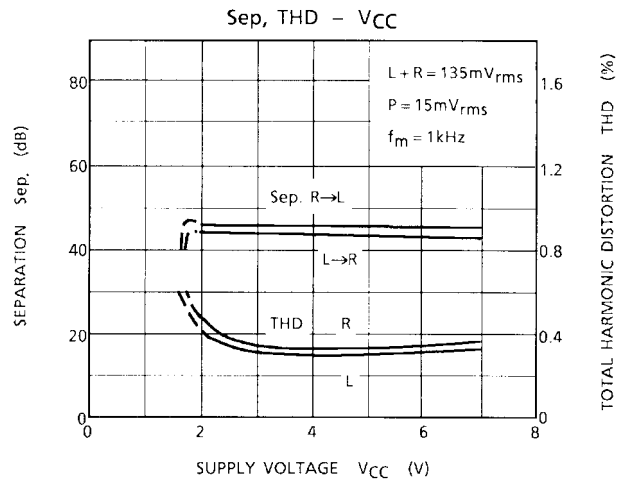
MPX



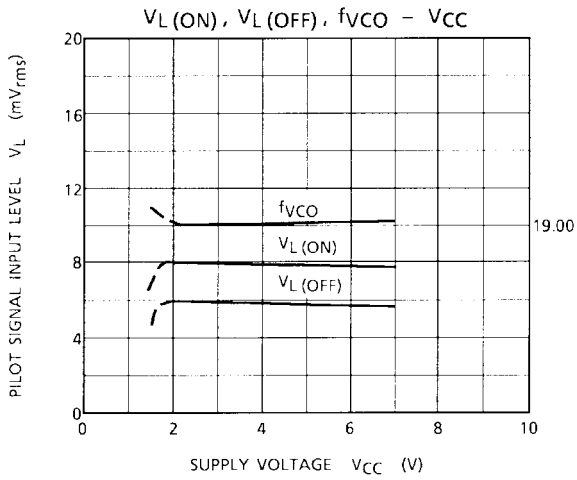
MPX



MPX



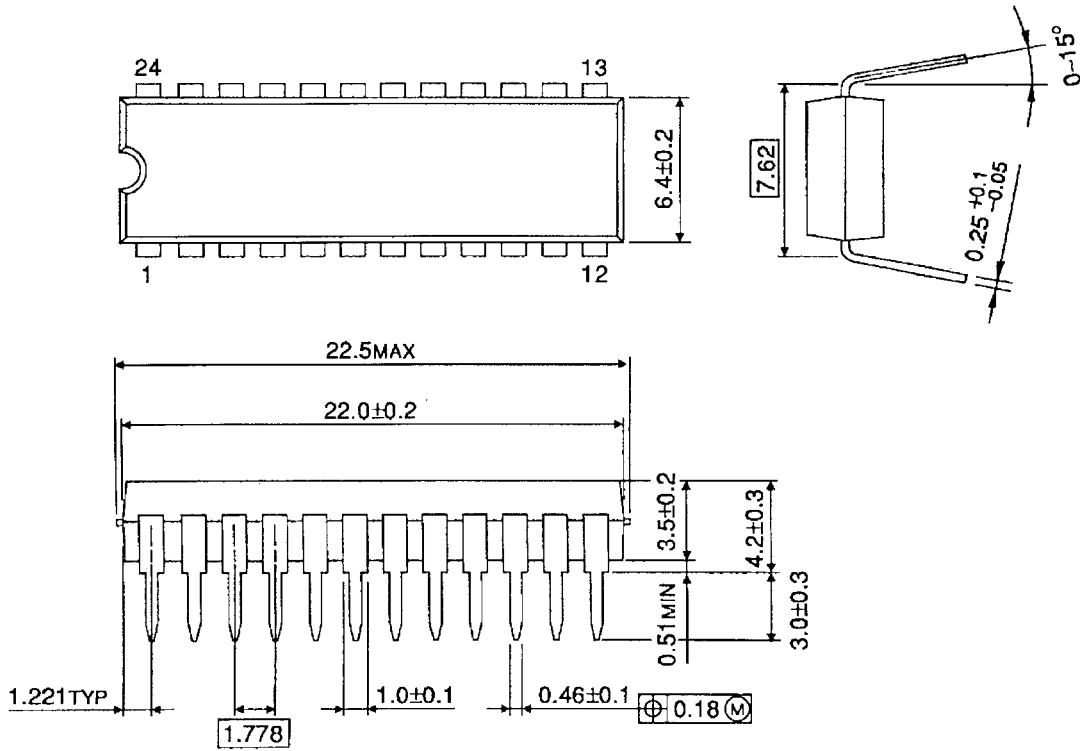
MPX



**Package Dimensions**

SDIP24-P-300-1.78

Unit : mm

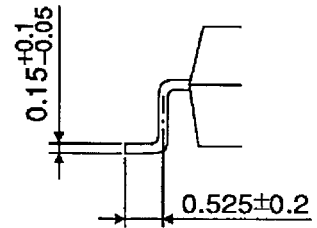
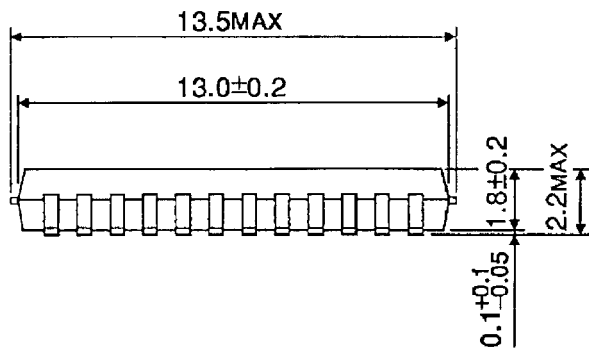
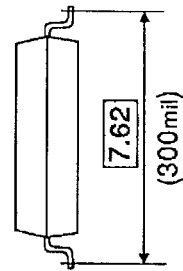
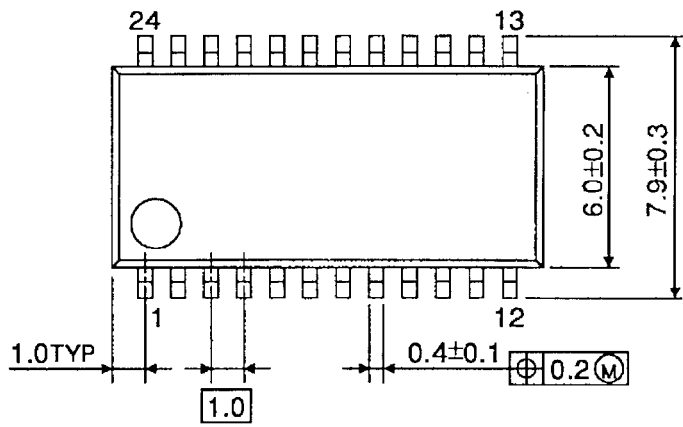


Weight: 1.2 g (typ.)

**Package Dimensions**

SSOP24-P-300-1.00

Unit : mm

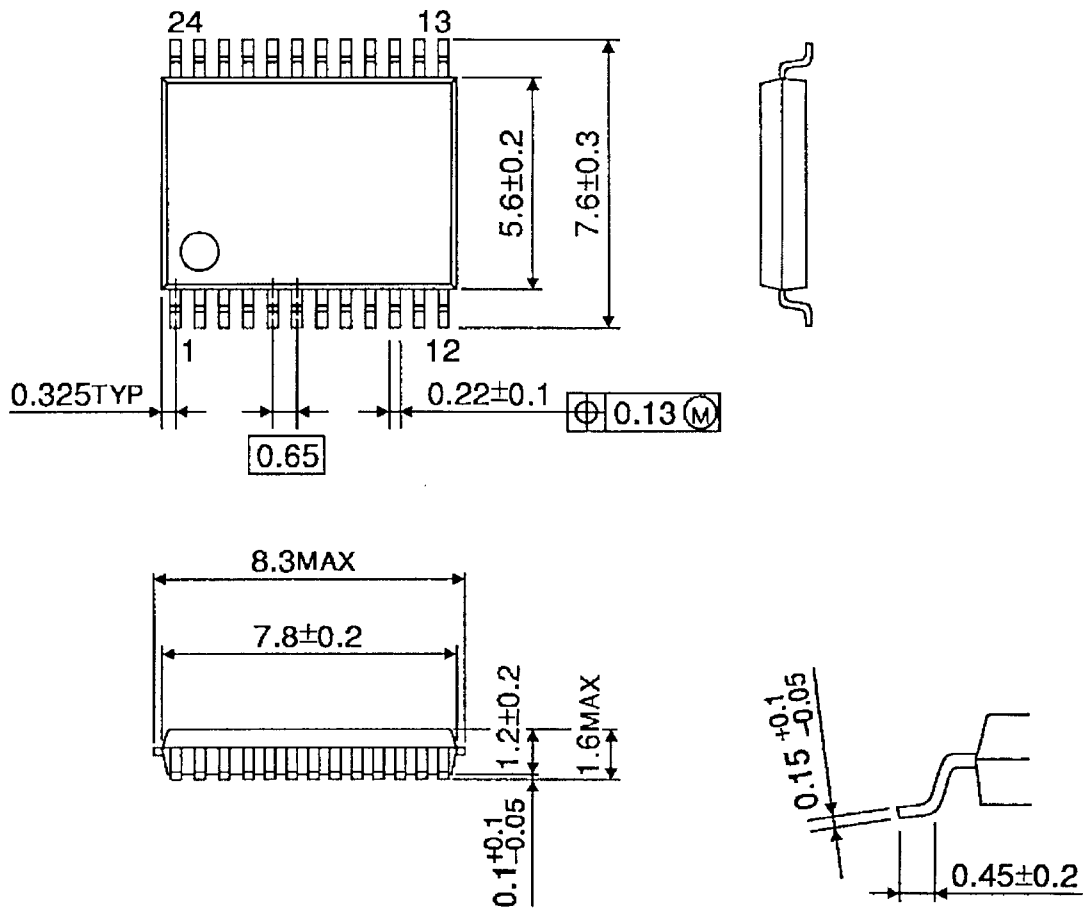


Weight: 0.31 g (typ.)

**Package Dimensions**

SSOP24-P-300-0.65A

Unit : mm



Weight: 0.14 g (typ.)



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000707EBA

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